

International Rectifier

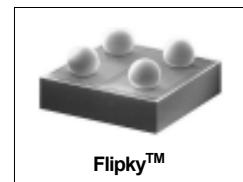
IR140CSP

Flipky™

1 Amp

Features

- Ultra Low V_F per Footprint Area
- Low Thermal Resistance
- One-fifth Footprint of SMA
- Super Low Profile (<.8mm)
- Available Tested on Tape & Reel

**Major Ratings and Characteristics**

Characteristics	IR140CPS	Units
$I_{F(AV)}$ Rectangular waveform	1.0	A
V_{RRM}	40	V
I_{FSM} @ $t_p = 5 \mu s$ sine	250	A
V_F @ 1.0 Apk, $T_J = 125^\circ C$	0.38	V
T_J range	-55 to 150	°C

Description

True chip-scale packaging is available from International Rectifier. The IR140CPS surface-mount Schottky rectifier has been designed for applications requiring low forward drop and very small foot prints on PC boards. Typical applications are in disk drives, switching power supplies, converters, free-wheeling diodes, battery charging, and reverse battery protection.

- Small foot print, surface mountable
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability

The Flipky™ package, is one-fifth the footprint of a comparable SMA package and has a profile of less than .8mm. Combined with the low thermal resistance of the die level device, this makes the Flipky™ the best device for application where printed circuit board space is at a premium and in extremely thin application environments such as battery packs, cell phones and PCMCIA cards.

IR140CSP

Bulletin I0148J rev. B 04/03

International
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Voltage Ratings

Part number	IR140CSP	
V_R Max. DC Reverse Voltage (V)		
V_{RWM} Max. Working Peak Reverse Voltage (V)		40

Absolute Maximum Ratings

Parameters	Value	Units	Conditions		
$I_{F(AV)}$ Max. Average Forward Current	1.0	A	50% duty cycle @ $T_{PCB} = 99^\circ\text{C}$, rectangular wave form		
I_{FSM} Max. Peak One Cycle Non-Repetitive Surge Current @ 25°C	250	A	5μs Sine or 3μs Rect. pulse	Following any rated load condition and with rated V_{RRM} applied	
	21		10ms Sine or 6ms Rect. pulse		
E_{AS} Non-Repetitive Avalanche Energy	10	mJ	$T_J = 25^\circ\text{C}$, $I_{AS} = 2.0\text{A}$, $L = 5.0\text{mH}$		
I_{AR} Repetitive Avalanche Current	2.0	A	Current decaying linearly to zero in 1 μsec Frequency limited by T_J max. $V_a = 1.5 \times V_r$ typical		

Electrical Specifications

Parameters	Typ.	Max.	Units	Conditions	
V_{FM} Max. Forward Voltage Drop * See Fig. 1	0.43	0.48	V	@ 1A	$T_J = 25^\circ\text{C}$
	0.51	0.56		@ 2A	
	0.34	0.38		@ 1A	$T_J = 125^\circ\text{C}$
	0.46	0.53		@ 2A	
I_{RM} Max. Reverse Leakage Current * See Fig. 2	10	80	μA	$T_J = 25^\circ\text{C}$	$V_R = \text{rated } V_R$
	3.5	20			$V_R = 20\text{V}$
	2	10			$V_R = 10\text{V}$
	1.5	5			$V_R = 5\text{V}$
	9.0	20	mA	$T_J = 125^\circ\text{C}$	$V_R = \text{rated } V_R$
	3.5	8			$V_R = 20\text{V}$
	2.5	6			$V_R = 10\text{V}$
	2	5			$V_R = 5\text{V}$
C_T Max. Junction Capacitance	-	160	pF	$V_R = 5\text{V}_{DC}$ (test signal range 100kHz to 1MHz) 25°C	
dv/dt Max. Volatge Rate of Charge	-	10000	V/μs	(Rated V_R)	

(1) Pulse Width < 300μs, Duty Cycle < 2%

Thermal-Mechanical Specifications

Parameters	Value	Units	Conditions	
T_J Max. Junction Temperature Range (*)	-55 to 150	°C		
T_{stg} Max. Storage Temperature Range	-55 to 150	°C		
R_{thJL} Typ. Thermal Resistance Junction to PCB (**)	55	°C/W	DC operation	
R_{thJA} Max. Thermal Resistance Junction to Ambient	75	°C/W		

(*) $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{th(j-a)}}$ thermal runaway condition for a diode on its own heatsink

(**) Mounted 1 inch square PCB

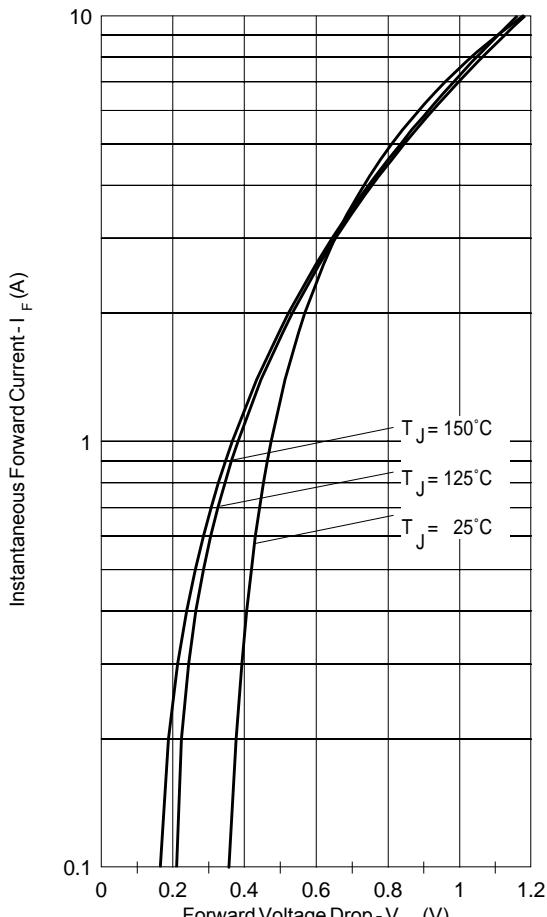


Fig. 1 - Max. Forward Voltage Drop Characteristics
 (Per Leg)

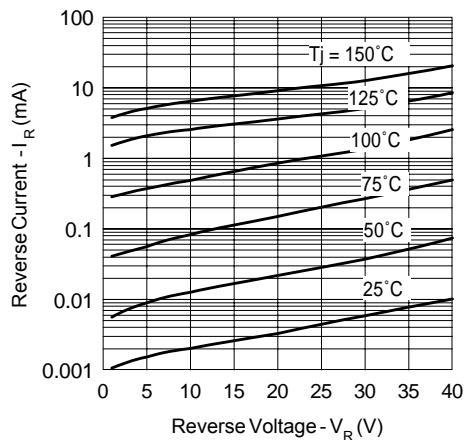


Fig. 2 - Typical Values Of Reverse Current
 Vs. Reverse Voltage (Per Leg)

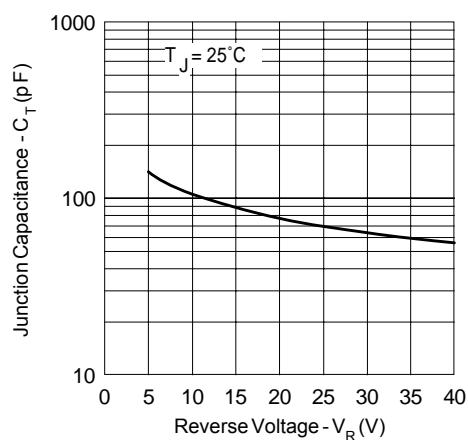


Fig. 3 - Typical Junction Capacitance
 Vs. Reverse Voltage (Per Leg)

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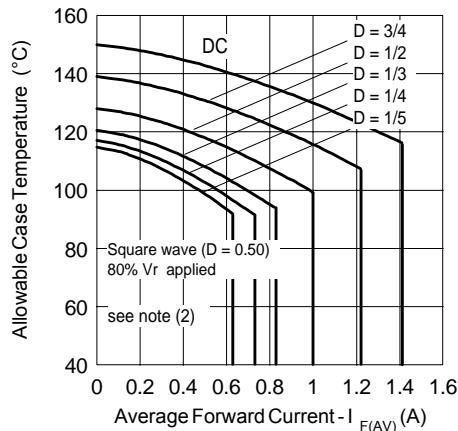


Fig. 4 - Max. Allowable Case Temperature Vs. Average Forward Current (Per Leg)

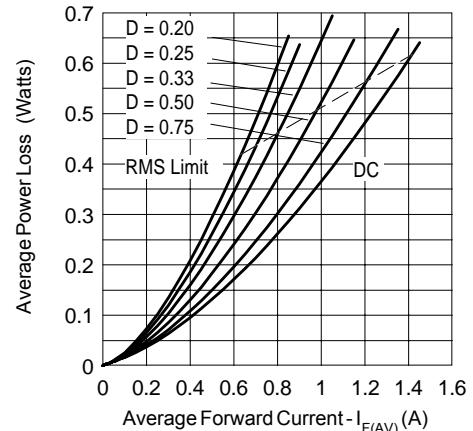


Fig. 5 - Forward Power Loss Characteristics (Per Leg)

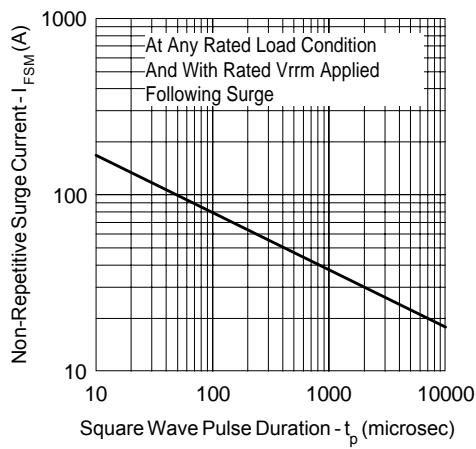


Fig. 6 - Max. Non-Repetitive Surge Current (Per Leg)

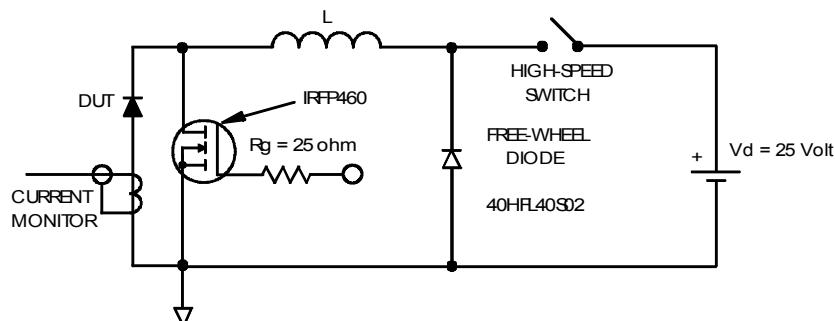
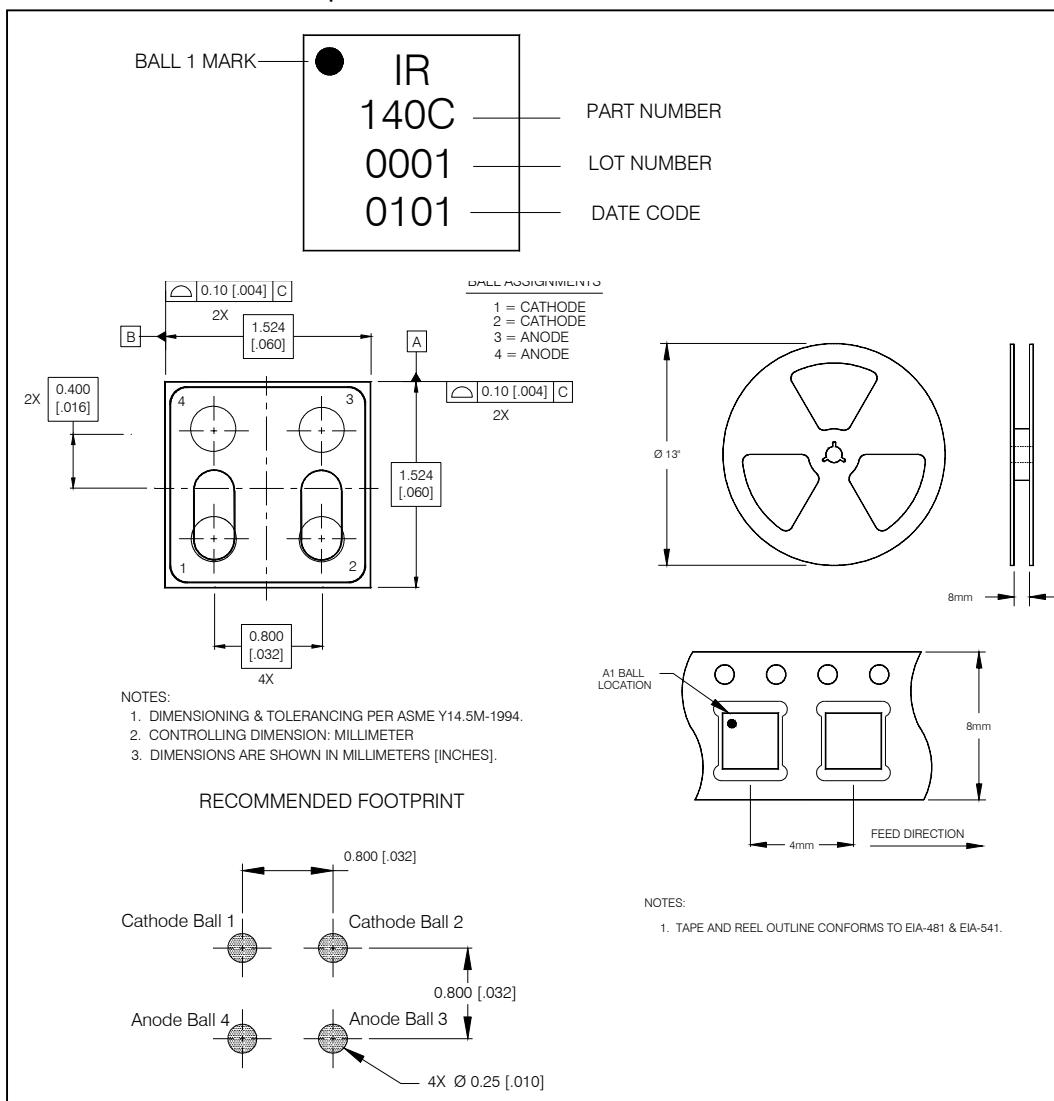


Fig. 8 - Unclamped Inductive Test Circuit

- (2) Formula used: $T_C = T_J - (P_d + P_{d,REV}) \times R_{thJC}$
 $P_d = \text{Forward Power Loss} = I_{F(AV)} \times V_{FM} @ (I_{F(AV)} / D)$ (see Fig. 6);
 $P_{d,REV} = \text{Inverse Power Loss} = V_{R1} \times I_R (1 - D); I_R @ 10V, 80\% V_R \text{ applied}$

Outline Dimension and Tape and Reel



Data and specifications subject to change without notice.
This product has been designed for Consumer Level.
Qualification Standards can be found on IR's Web site.

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